TOSHIBA TLP206G

TOSHIBA PHOTOCOUPLER GaAs IRED & PHOTO-MOS FET

TLP206G

PBX

MODEM · FAX CARD

MEASUREMENT INSTRUMENT

The TOSHIBA TLP206G consists of gallium arsenide infrared emitting diode optically coupled to a photo-MOS FET in a 8 pin SOP. The TLP206G is a 2-Form-A switch which is suitable for replacement of mechanical relays in many applications.

SOP 8 pin (2.54SOP8) : 2-Form-A

Peak Off-State Voltage: 350 V (min) Trigger LED Current : 3 mA (max) On-State Current : 120 mA (max) On-State Resistance : 35 Ω (max) Isolation Voltage : $1500 \, V_{rms}$ (min)

UL Recognized : UL1577, File No. E67349

BSI Approved : BS EN60065 : 1994, Certificate No. 8273

BS EN60950: 1992, Certificate No. 8274

SEMKO Approved: SS EN60065

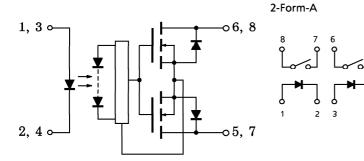
SS EN60950

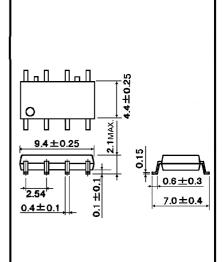
Option (V4) type

TUV Approved: DIN VDE0884/06.92,

Certificate No. R9850580

SCHEMATIC





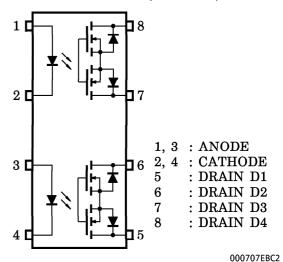
Unit in mm

TOSHIBA Weight: 0.2 g

JEDEC

EIAJ

PIN CONFIGURATION (TOP VIEW)



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TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.

In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..

The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.

2000-08-28

1/5

MAXIMUM RATINGS (Ta = 25°C)

	CHARACTE	SYMBOL	RATING	UNIT		
	Forward Current	${ m I_F}$	50	mA		
	Forward Current Derating	ΔI _F /°C	-0.5	mA/°C		
LED	Pulse Forward Current (10	$I_{ extbf{FP}}$	1	A		
17	Reverse Voltage	$v_{ m R}$	5	V		
	Junction Temperature	$T_{\rm j}$	125	°C		
	Off-State Output Terminal	V _{OFF}	350	V		
CTOR	On State Comment	Both Channel (Note 1)	T	100	A	
CI	On-State Current	One Channel	I_{ON}	120	mA	
TE	On-State RMS Current	Both Channel (Note 1)	41 / 90	-1.0	A / O	
DE.	Derating (Ta ≥ 25 °C)	One Channel	∆I _{ON} / °C	-1.2	mA/°C	
Γ	Junction Temperature	$T_{ m j}$	125	°C		
Sto	orage Temperature Range	$ m T_{stg}$	-55~125	°C		
Op	erating Temperature Range	$\mathrm{T}_{\mathrm{opr}}$	-40~85	$^{\circ}\mathrm{C}$		
Le	ad Soldering Temperature ($T_{ m sol}$	260	$^{\circ}\mathrm{C}$		
Iso	lation Voltage (AC, 1 min.,	$BV_{\mathbf{S}}$	1500	V_{rms}		

(Note 1): Two channels operating simultaneously.

(Note 2): Device considered a two-terminal device: pins 1, 2, 3 and 4 shorted

together and pins 5, 6, 7 and 8 shorted together.

RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	$V_{ m DD}$	_	_	280	V
Forward Current	${f I_F}$	5	7.5	25	mA
On-State Current	I_{ON}	_	_	100	mA
Operating Temperature	$\mathrm{T}_{\mathrm{opr}}$	-20	_	65	$^{\circ}\mathrm{C}$

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Gallium arsenide (GaAs) is a substance used in the products described in this document. GaAs dust and fumes are toxic. Do not break, cut or pulverize the product, or use chemicals to dissolve them. When disposing of the products, follow the appropriate regulations. Do not dispose of the products with other industrial waste or with domestic garbage.

The products described in this document are subject to the foreign exchange and foreign trade laws.

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.

The information contained herein is subject to change without notice.

INDIVIDUAL ELECTRICAL CHARACTERISTICS (Ta = 25°C)

	CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
	Forward Voltage	$V_{\mathbf{F}}$	$I_{ m F}=10~{ m mA}$	1.0	1.15	1.3	V
LED	Reverse Current	${ m I}_{ m R}$	$V_{R} = 5 V$	_	_	10	μ A
Γ	Capacitance	C_{T}	V = 0, $f = 1 MHz$	_	30	_	pF
CTOR	Off-State Current	$I_{ m OFF}$	$ m V_{OFF} = 350~V$		_	1	μ A
DETEC	Capacitance	c_{OFF}	V = 0, f = 1 MHz	-	40	-	pF

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Trigger LED Current	I_{FT}	$I_{ON} = 120 \text{mA}$	_	1	3	mA
On-State Resistance	RON	$I_{ON} = 120 \mathrm{mA}, \; I_{F} = 5 \mathrm{mA}$	_	22	35	Ω

ISOLATION CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance Input to Output	c_{S}	$V_S = 0$, $f = 1 MHz$	_	0.8	_	рF
Isolation Resistance	$R_{\mathbf{S}}$	$V_{S} = 500 V, \text{ R.H.} \le 60\%$	5×10^{10}	10^{14}		Ω
		AC, 1 minute	1500	_	V_rr	37
Isolation Voltage	$_{ m BV_S}$	AC, 1 second, in oil	_	3000	_	$V_{ m rms}$
		DC, 1 minute, in oil	_	3000	_	Vdc

SWITCHING CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Turn-on Time	$t_{ m ON}$	$R_L = 200 \Omega$ (Note 3)	_	0.3	1	ma
Turn-off Time	$t_{ m OFF}$	$ m V_{DD} = 20~V,~I_F = 5~mA$	_	0.1	1	ms

(Note 3): Switching Time Test Circuit

